



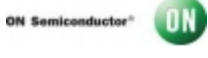






	<h2 style="color: red;">NTB30N20T4G</h2>	
	Hersteller-Teilenummer:	NTB30N20T4G
	Hersteller / Marke:	AMI Semiconductor / ON Semiconductor
	Teil der Beschreibung:	MOSFET N-CH 200V 30A D2PAK
Datenblätter:	 NTB30N20T4G.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 46288 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	NTB30N20T4G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET N-CH 200V 30A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	46288 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	2W (Ta), 214W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	30A (Ta)
Rds On (Max) @ Id, Vgs	81 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	100nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2335pF @ 25V
Verpackung	Tape & Reel (TR)

















































NTB30N20T4G ist neu im Original, Suche NTB30N20T4G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTB30N20T4G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTB30N20T4G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NTB30N20 AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 30A D2PAK</p>	 <p>NTB30N20T4 AMI Semiconductor / ON Semiconductor NTB30N20T4 ON</p>	 <p>NTB30P06VT4G ON ON TO-263</p>	 <p>NTB35N15G AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 37A D2PAK</p>
 <p>NTB35N15T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 150V 37A D2PAK</p>	 <p>NTB30N06T4G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 27A D2PAK</p>	 <p>NTB35N15 ON NTB35N15 ON</p>	 <p>NTB30N06T4 AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 27A D2PAK</p>

heiße Teile

Mehr

 NTB13N10T4G	 NTB18N06G	 NTB18N06L	 NTB18N06LG	 NTB18N06LT4
 NTB18N06LT4G	 NTB18N06T4G	 NTB23N03RG	 NTB23N03RT4	 NTB23N03RT4G
 NTB25P06	 NTB25P06G	 NTB25P06T4	 NTB25P06T4G	 NTB27N06T4G
 NTB30N06G	 NTB30N06L	 NTB30N06LG	 NTB30N06LT4	 NTB30N06LT4G
 NTB30N06T4	 NTB30N06T4G	 NTB30N20	 NTB30N20G	 NTB30N20T4
 NTB35N15	 NTB35N15G	 NTB35N15T4G	 NTB35N15T4G	 NTB4302G
 NTB4302T4G	 NTB45N06G	 NTB45N06L	 NTB45N06LG	 NTB45N06LT4
 NTB45N06LT4G	 NTB45N06T4	 NTB45N06T4G	 NTB52N10	 NTB52N10G
 NTB52N10T4G	 NTB5404N	 NTB5404NT4G	 NTB5405N	 NTB5405NG
 NTB5405NT4G	 NTB5411N	 NTB5411NG	 NTB5411NT4G	 NTB5411NUTUMC

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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